

Photointerrupters(Reflective)

KODENSHI

SG - 2BC

The SG - 2BC reflective sensor combines a GaAs IRED with a high - sensitivity phototransistor in a super - mini (4) ceramic package, reducing installation space.

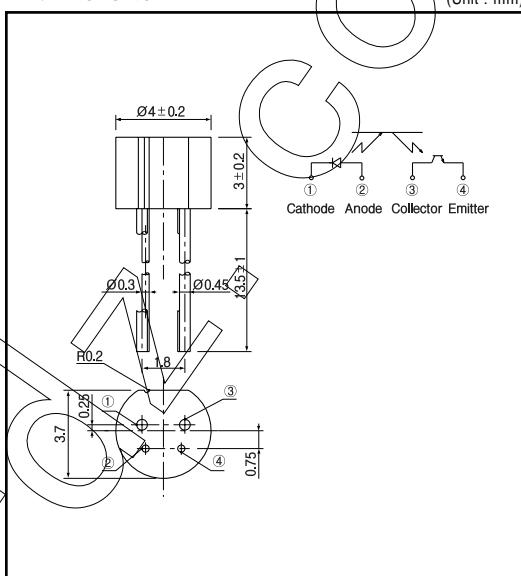
FEATURES

- Compact ($\phi 4\text{mm}$)
- High performance
- High - speed response
- Easy to mount on P.C.B.
- Widely applicable

APPLICATIONS

- Timing sensors
- Edge sensors
- Micro floppy disk drives
- Level sensors of liquid

DIMENSIONS



MAXIMUM RATINGS

Item	Symbol	Rating	Unit
Input	P _D	75	mW
	V _R	5	V
	I _F	50	mA
	I _{FP}	1	A
Output	P _C	75	mW
	I _C	20	mA
	V _{CEO}	30	V
	V _{ECD}	3	V
	Operating temp.	T _{opr.} - 20 ~ 90	
	Storage temp.	T _{stg.} - 30 ~ +100	
Soldering temp.	T _{sol.}	260	

*1. t w 100 μsec . period : T=10msec.

*2. For MAX. 5 seconds at the position of 2mm from the package

ELECTRO-OPTICAL CHARACTERISTICS

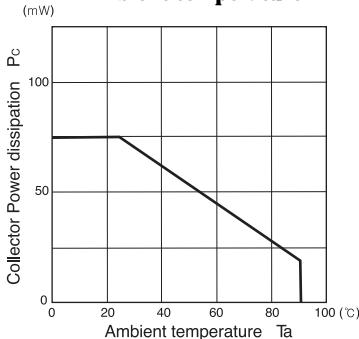
(Ta=25 °C)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Input	V _F	I = 4mA			1.2	V
	I _R	V _R =5V			10	μA
	C _t	V=0V, f=1KHz		25		pF
	λ_p			940		nm
Output	I _{CEO}	V _{CE} =10V			0.1	μA
	I _L	V _{CE} =2V, I=4mA		100		μA
	I _{CEO'D}	V _{CE} =2V, I=4mA			0.1	μA
Switching speeds	tr			30		$\mu\text{sec.}$
	tf	V _{CC} =2V, I=100 μA , R=1k		30		$\mu\text{sec.}$

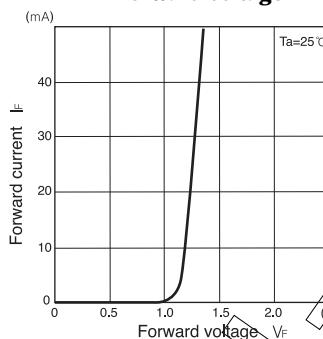
Photo interrupters(Reflective)

SG - 2BC

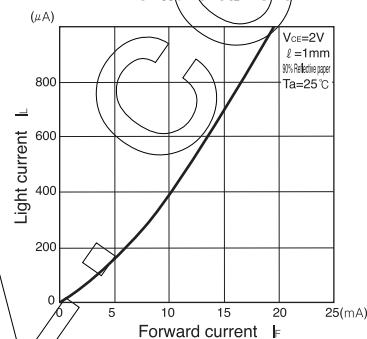
**Collector power dissipation Vs.
Ambient temperature**



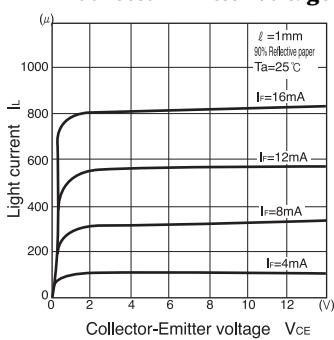
**Forward current Vs.
Forward voltage**



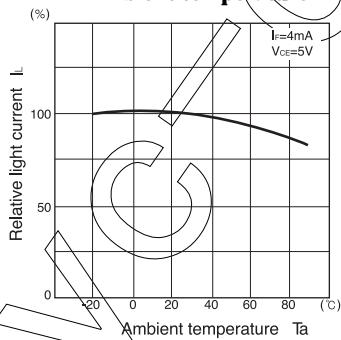
**Light current Vs.
Forward current**



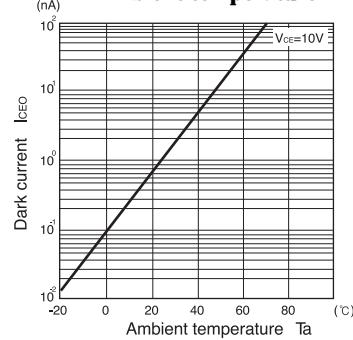
**Light current Vs.
Collector-Emitter voltage**



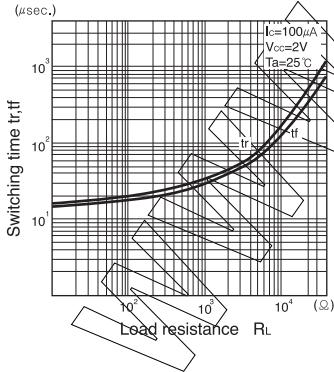
**Relative light current Vs.
Ambient temperature**



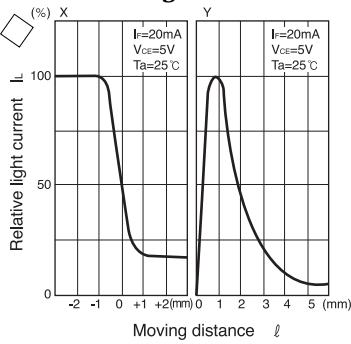
**Dark current Vs.
Ambient temperature**



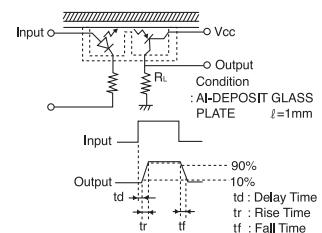
**Switching time Vs.
Load resistance**



**Relative light current Vs.
Moving distance**



Switching time measurement circuit



Method of measuring position characteristic

